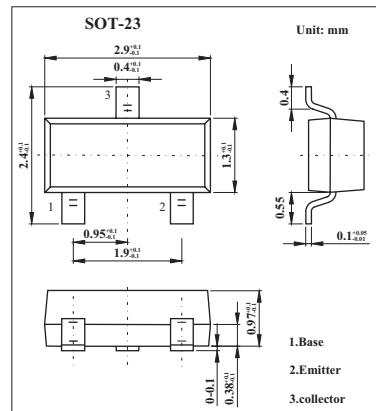


# FMMT455

## ■ Features

- 140 Volt V<sub>CEO</sub>
- 1 Amp continuous current
- P<sub>tot</sub> = 500 mW



## ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	160	V
Collector-emitter voltage	V <sub>CEO</sub>	140	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Peak collector current	I <sub>CM</sub>	2	A
Collector current	I <sub>C</sub>	1	A
Base current	I <sub>B</sub>	200	mA
Power dissipation	P <sub>tot</sub>	500	mW
Operating and storage temperature range	T <sub>j</sub> , T <sub>stg</sub>	-55 to +150	°C

## ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100µA	160			V
Collector-emitter sustaining voltage *	V <sub>CEO(sus)</sub>	I <sub>C</sub> =10mA	140			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100µA	5			V
Collector cutoff current	I <sub>CBO</sub>	V <sub>CB</sub> =140V			0.1	µA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =4V			0.1	µA
Collector-emitter saturation voltage *	V <sub>CE(sat)</sub>	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			0.7	V
Static Forward Current Transfer Ratio	h <sub>FE</sub>	I <sub>C</sub> =150mA, V <sub>CE</sub> =10V *	100		300	
		I <sub>C</sub> =1A, V <sub>CE</sub> =10V*		10		
Transition frequency	f <sub>T</sub>	I <sub>C</sub> =50mA, V <sub>CE</sub> =10V, f=100MHz	100			MHz
Output capacitance	C <sub>obo</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz			15	pF

\* Pulse test: t<sub>p</sub> = 300 µs; d ≤ 0.02.

## ■ Marking

Marking	455
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